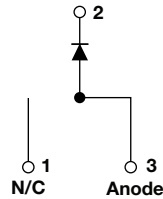


HEXFRED® Ultrafast Soft Recovery Diode, 6 A


D²PAK

FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Specified at operating conditions
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- AEC-Q101 qualified


RoHS
 COMPLIANT
 HALOGEN
FREE
BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA06TB120S is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 6 A continuous current, the VS-HFA06TB120S is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to “snap-off” during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA06TB120S is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

PRODUCT SUMMARY

| | |
|--------------------------------------|----------------|
| V_R | 1200 V |
| V_F at 6 A at 25 °C | 3.0 V |
| $I_{F(AV)}$ | 6 A |
| t_{rr} (typical) | 26 ns |
| T_J (maximum) | 150 °C |
| Q_{rr} (typical) | 116 nC |
| $dI_{(rec)M}/dt$ (typical) at 125 °C | 100 A/ μ s |
| I_{RRM} (typical) | 4.4 A |

ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
|--|----------------|-----------------------|---------------|-------|
| Cathode to anode voltage | V_R | | 1200 | V |
| Maximum continuous forward current | I_F | $T_C = 100\text{ °C}$ | 6 | A |
| Single pulse forward current | I_{FSM} | | 80 | |
| Maximum repetitive forward current | I_{FRM} | | 24 | |
| Maximum power dissipation | P_D | $T_C = 25\text{ °C}$ | 62.5 | W |
| | | $T_C = 100\text{ °C}$ | 25 | |
| Operating junction and storage temperature range | T_J, T_{Stg} | | - 55 to + 150 | °C |

| ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified) | | | | | | |
|---|----------|--|------|------|------|---------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage | V_{BR} | $I_R = 100\text{ }\mu\text{A}$ | 1200 | - | - | V |
| Maximum forward voltage | V_{FM} | $I_F = 6.0\text{ A}$ | - | 2.7 | 3.0 | |
| | | $I_F = 12\text{ A}$ | - | 3.5 | 3.9 | |
| | | $I_F = 6.0\text{ A}, T_J = 125\text{ }^\circ\text{C}$ | - | 2.4 | 2.8 | |
| Maximum reverse leakage current | I_{RM} | $V_R = V_R\text{ rated}$ | - | 0.26 | 5.0 | μA |
| | | $T_J = 125\text{ }^\circ\text{C}, V_R = 0.8 \times V_R\text{ rated}$ | - | 110 | 500 | |
| Junction capacitance | C_T | $V_R = 200\text{ V}$ | - | 9.0 | 14 | pF |
| Series inductance | L_S | Measured lead to lead 5 mm from package body | - | 8.0 | - | nH |

| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified) | | | | | | |
|--|-------------------|---|------|------|------|------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Reverse recovery time | t_{rr} | $I_F = 1.0\text{ A}, di_F/dt = 200\text{ A}/\mu\text{s}, V_R = 30\text{ V}$ | - | 26 | - | ns |
| | t_{rr1} | $T_J = 25\text{ }^\circ\text{C}$ | - | 53 | 80 | |
| | t_{rr2} | $T_J = 125\text{ }^\circ\text{C}$ | - | 87 | 130 | |
| Peak recovery current | I_{RRM1} | $T_J = 25\text{ }^\circ\text{C}$ | - | 4.4 | 8.0 | A |
| | I_{RRM2} | $T_J = 125\text{ }^\circ\text{C}$ | - | 5.0 | 9.0 | |
| Reverse recovery charge | Q_{rr1} | $T_J = 25\text{ }^\circ\text{C}$ | - | 116 | 320 | nC |
| | Q_{rr2} | $T_J = 125\text{ }^\circ\text{C}$ | - | 233 | 585 | |
| Peak rate of recovery current during t_b | $di_{(rec)M}/dt1$ | $T_J = 25\text{ }^\circ\text{C}$ | - | 180 | - | $\text{A}/\mu\text{s}$ |
| | $di_{(rec)M}/dt2$ | $T_J = 125\text{ }^\circ\text{C}$ | - | 100 | - | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|------------|--|------|------|------|------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Lead temperature | T_{lead} | 0.063" from case (1.6 mm) for 10 s | - | - | 300 | $^\circ\text{C}$ |
| Thermal resistance, junction to case | R_{thJC} | | - | - | 2.0 | K/W |
| Thermal resistance, junction to ambient | R_{thJA} | Typical socket mount | - | - | 80 | |
| Thermal resistance, case to heatsink | R_{thCS} | Mounting surface, flat, smooth and greased | - | 0.5 | - | |
| Weight | | | - | 2.0 | - | g |
| | | | - | 0.07 | - | oz. |



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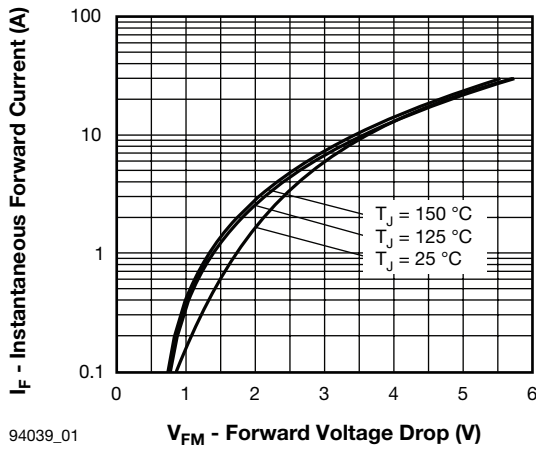


Fig. 1 - Typical Forward Voltage Drop Characteristics

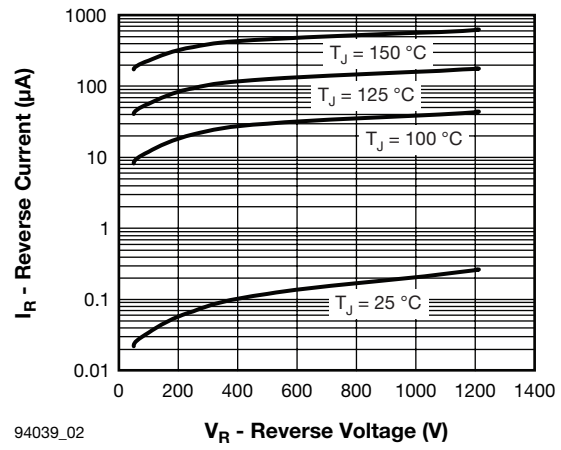


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

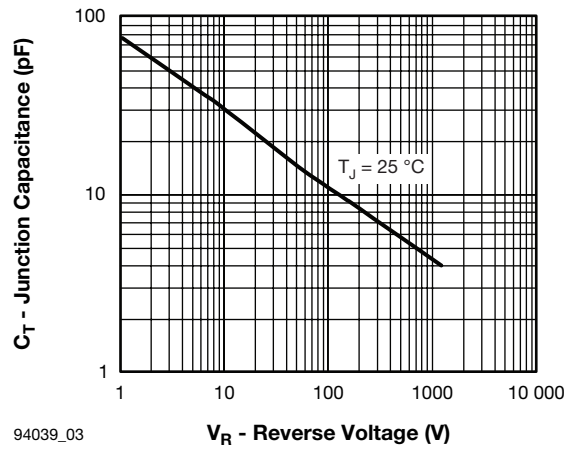


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

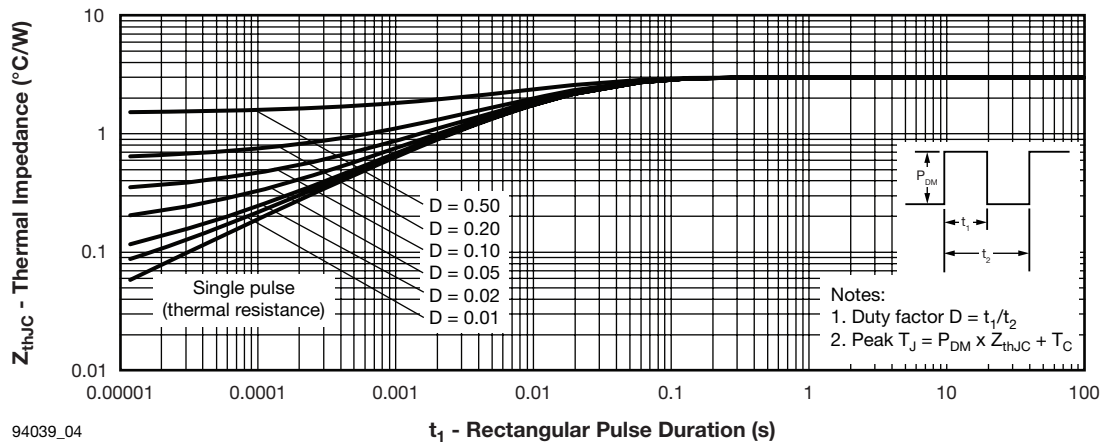


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

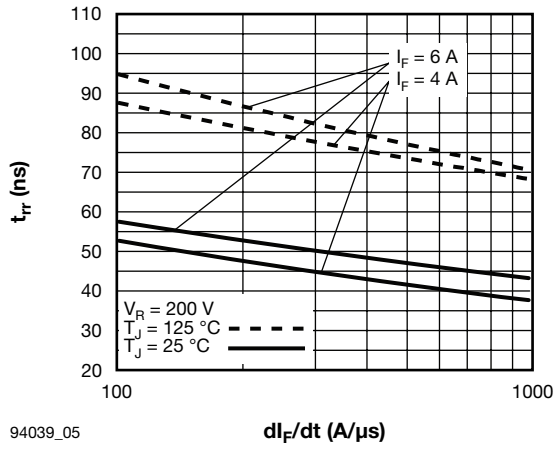


Fig. 5 - Typical Reverse Recovery Time vs. di_F/dt

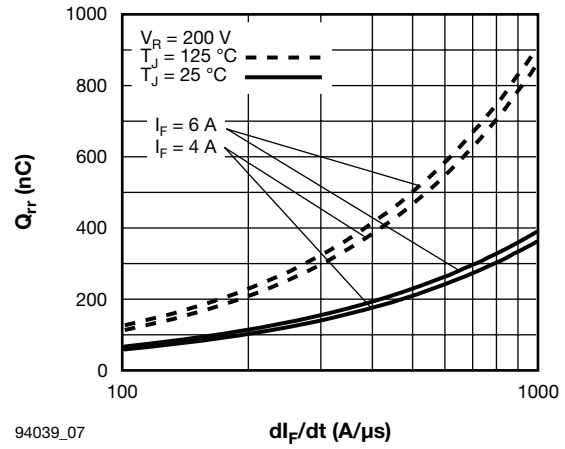


Fig. 7 - Typical Stored Charge vs. di_F/dt

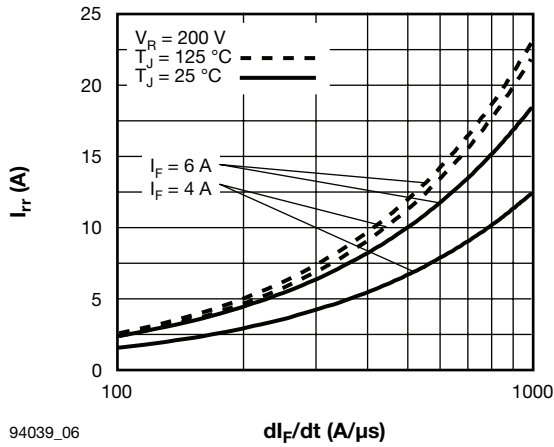


Fig. 6 - Typical Recovery Current vs. di_F/dt

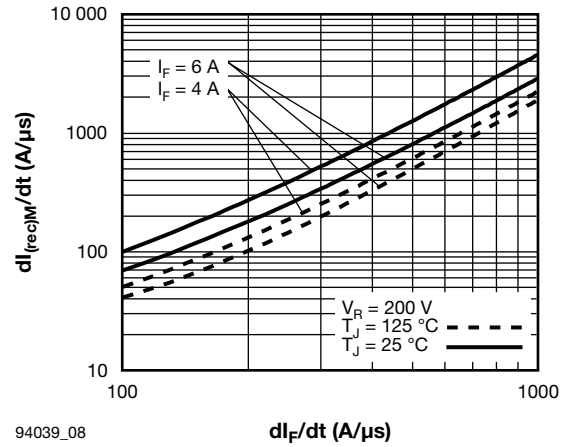


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. di_F/dt

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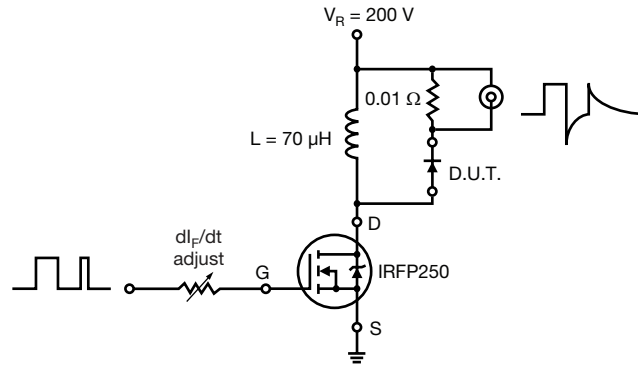
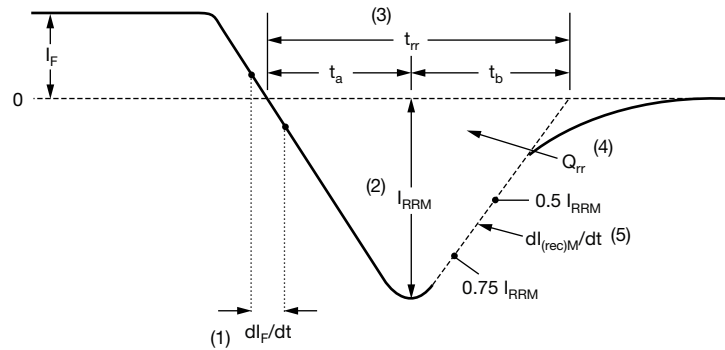


Fig. 9 - Reverse Recovery Parameter Test Circuit


 (1) di_F/dt - rate of change of current through zero crossing

 (2) I_{RRM} - peak reverse recovery current

 (3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.5 I_{RRM}$ extrapolated to zero current.

 (4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

 (5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

VS-HFA06TB120SPbF

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ORDERING INFORMATION TABLE

| | | | | | | | | | |
|-------------|-----|----|---|----|----|-----|---|-----|-----|
| Device code | VS- | HF | A | 06 | TB | 120 | S | TRL | PbF |
| | ① | ② | ③ | ④ | ⑤ | ⑥ | ⑦ | ⑧ | ⑨ |

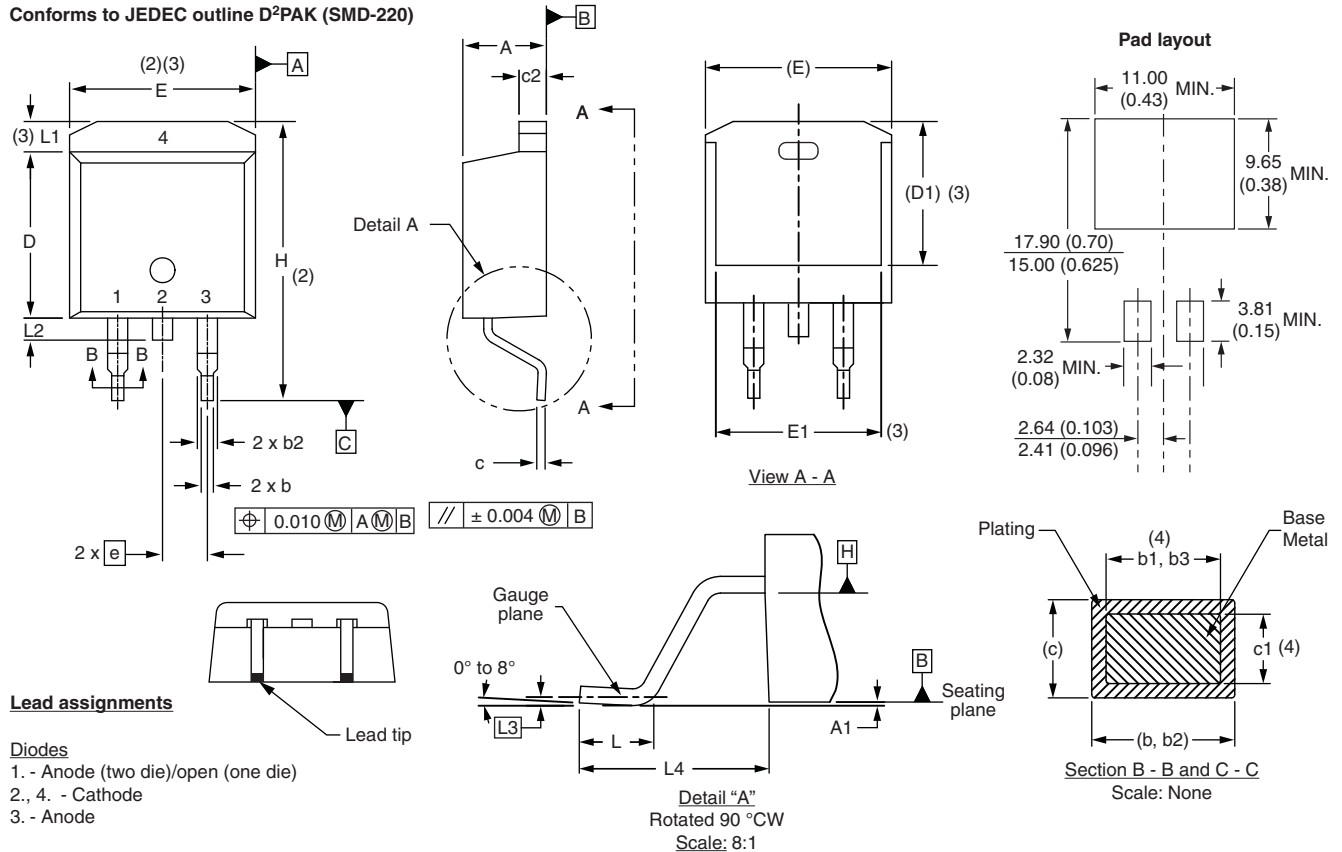
- 1** - HPP product suffix
- 2** - HEXFRED® family
- 3** - Process designator: A = Electron irradiated
- 4** - Current rating (06 = 6 A)
- 5** - Package outline (TB = TO-220, 2 leads)
- 6** - Voltage rating (120 = 1200 V)
- 7** - S = D²PAK
- 8** -
 - None = Tube (50 pieces)
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 9** - PbF = Lead (Pb)-free

| LINKS TO RELATED DOCUMENTS | |
|----------------------------|--|
| Dimensions | www.vishay.com/doc?95046 |
| Part marking information | www.vishay.com/doc?95054 |
| Packaging information | www.vishay.com/doc?95032 |

D²PAK

DIMENSIONS in millimeters and inches

Conforms to JEDEC outline D²PAK (SMD-220)



| SYMBOL | MILLIMETERS | | INCHES | | NOTES | SYMBOL | MILLIMETERS | | INCHES | | NOTES |
|--------|-------------|-------|--------|-------|-------|--------|-------------|-------|-----------|-------|-------|
| | MIN. | MAX. | MIN. | MAX. | | | MIN. | MAX. | MIN. | MAX. | |
| A | 4.06 | 4.83 | 0.160 | 0.190 | | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | e | 2.54 BSC | | 0.100 BSC | | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | H | 14.61 | 15.88 | 0.575 | 0.625 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| c | 0.38 | 0.74 | 0.015 | 0.029 | | L1 | - | 1.65 | - | 0.066 | 3 |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | L3 | 0.25 BSC | | 0.010 BSC | | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

- Dimensioning and tolerancing per ASME Y14.5 M-1994
- Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- Thermal pad contour optional within dimension E, L1, D1 and E1
- Dimension b1 and c1 apply to base metal only
- Datum A and B to be determined at datum plane H
- Controlling dimension: inch
- Outline conforms to JEDEC outline TO-263AB



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